UNR32AFG

Silicon NPN epitaxial planar type

For digital circuits

Features

• Suitable for high-density mounting and downsizing of the equipment

• Contribute to low power consumption

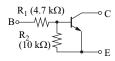
Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	50	V	
Collector current	I _C	80	mA	
Total power dissipation	P _T	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	





- SSSMini3-F2
- Marking Symbol: KD
- Pin Name
 - 1: Base
 - 2: Emitter
 - 3: Collector
- Internal Connection



Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$	50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$	50			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			1.0	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	30			_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$			0.25	V
Output voltage high-level	V _{OH}	$V_{CC} = 5 V, V_B = 0.5 V, R_L = 1 k\Omega$	4.9			V
Output voltage low-level	V _{OL}	$V_{CC} = 5 V, V_B = 2.5 V, R_L = 1 k\Omega$			0.2	V
Input resistance	R ₁		-30%	4.7	+30%	kΩ
Resistance ratio	R_1/R_2		0.37	0.47	0.57	_
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

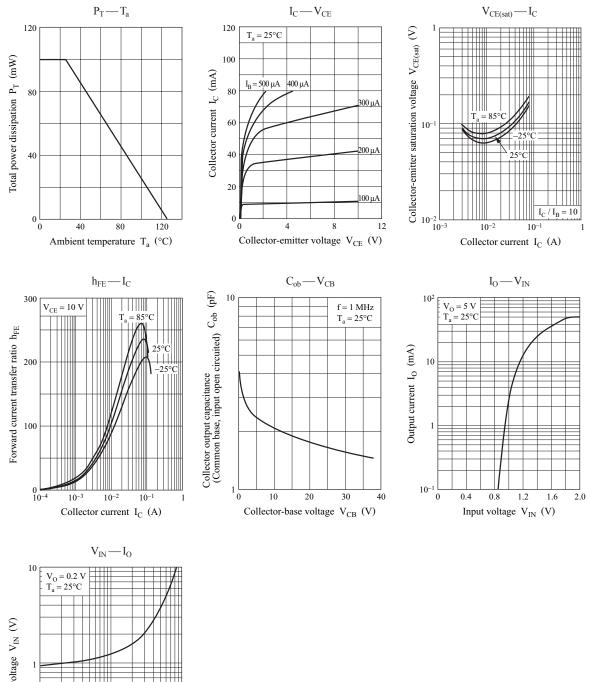
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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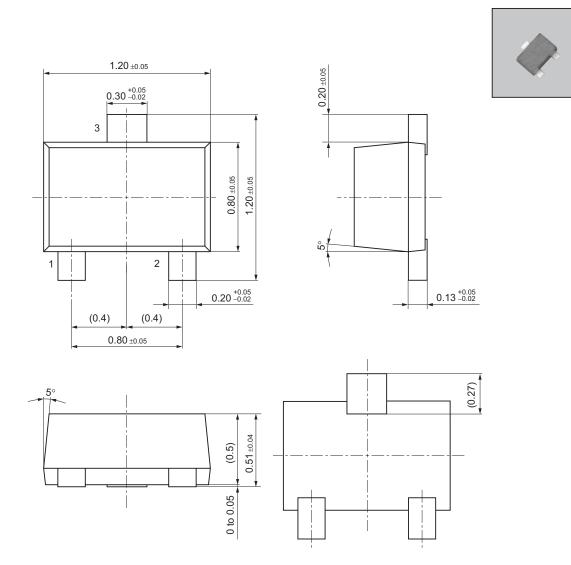
Panasonic



Input voltage V_{IN} (V) 10^{−1} ∟ 1 10 10^{2} Output current I_O (mA)

SSSMini3-F2





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